



GANE350-700BBA

700 V, 350 mOhm Gallium Nitride (GaN) FET in DPAK package

13 March 2025

Product data sheet

1. General description

The GANE350-700BBA is a general purpose 700 V, 350 m Ω Gallium Nitride (GaN) FET in a DPAK package. It is a normally-off e-mode device offering superior performance.

2. Features and benefits

- Enhancement mode - normally-off power switch
- Ultra high frequency switching capability
- No body diode
- Low gate charge, low output charge
- Qualified for standard applications
- ESD protection
- RoHS, Pb-free, REACH-compliant
- High efficiency and high power density

3. Applications

- High power density and high efficiency power conversion
- AC-to-DC converters, totem pole PFC
- DC-to-DC converters
- Fast battery charging, mobile phone, laptop, tablet and USB type-C chargers
- Datacom and telecom (AC-to-DC and DC-to-DC) converters
- Motor drives
- Solar (PV) inverters
- Class D audio amplifiers, TV PSU and LED drivers

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$-55\text{ }^{\circ}\text{C} \leq T_j \leq 150\text{ }^{\circ}\text{C}$	-	-	700	V
V_{TDS}	transient drain to source voltage	$t_p < 200\text{ }\mu\text{s}$	[1]	-	800	V
I_D	drain current	$V_{GS} = 6\text{ V}; T_{mb} = 25\text{ }^{\circ}\text{C}; \text{Fig. 2}$	[2]	-	6	A
P_{tot}	total power dissipation	$T_{mb} = 25\text{ }^{\circ}\text{C}; \text{Fig. 1}$	-	-	47	W
T_j	junction temperature		-55	-	150	$^{\circ}\text{C}$
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 6\text{ V}; I_D = 2.2\text{ A}; T_j = 25\text{ }^{\circ}\text{C}; \text{Fig. 12}; \text{Fig. 13}; \text{Fig. 14}$	-	270	350	m Ω
		$V_{GS} = 6\text{ V}; I_D = 2.2\text{ A}; T_j = 150\text{ }^{\circ}\text{C}; \text{Fig. 12}; \text{Fig. 15}$	-	580	-	m Ω
R_G	gate resistance	$f = 5\text{ MHz}; T_j = 25\text{ }^{\circ}\text{C}; \text{open drain}$	-	11	-	Ω

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Dynamic characteristics						
Q_{GD}	gate-drain charge	$I_D = 2.2\text{ A}$; $V_{DS} = 400\text{ V}$; $V_{GS} = 6\text{ V}$; $T_j = 25\text{ °C}$; Fig. 16 ; Fig. 17	-	0.5	-	nC
$Q_{G(\text{tot})}$	total gate charge	$T_j = 25\text{ °C}$; Fig. 16 ; Fig. 17	-	1.5	-	nC
Q_{oss}	output charge	$V_{GS} = 0\text{ V}$; $V_{DS} = 400\text{ V}$; $T_j = 25\text{ °C}$; Fig. 22	[3]	13	-	nC

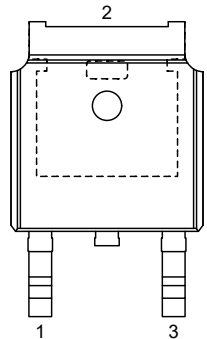
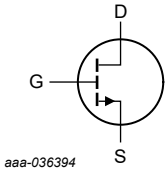
[1] Intended for non-repetitive events

[2] Limited by device saturation

[3] Q_r is not specified separately from Q_{oss} for e-mode GaN FETs, since $Q_r = Q_{oss} + Q_D$, and $Q_D = 0$. (Q_D is charge associated with diffusion of minority carriers. Since there is no body diode, no minority carriers in excess of Q_{oss} have to be transferred for e-mode GaN FETs.)

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	 <p>TO252 (SOT428-2)</p>	 <p>aaa-036394</p>
2	S	source		
3	D	drain		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
GAN350-700BBA	TO252	plastic, single-ended surface-mounted package (DPAK); 3 leads; 2.286 mm pitch; 6.1 mm x 6.6 mm x 2.3 mm body	SOT428-2

7. Marking

Table 4. Marking codes

Type number	Marking code
GAN350-700BBA	350SBBA

8. Limiting values

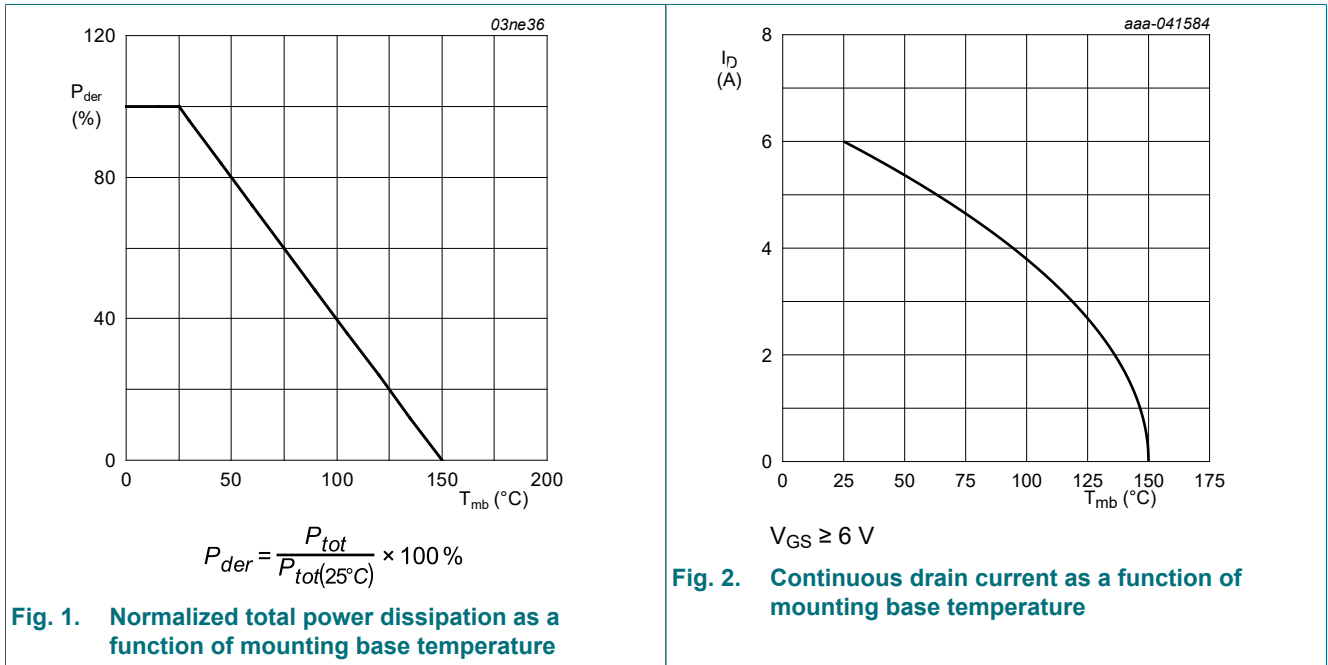
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$-55\text{ °C} \leq T_j \leq 150\text{ °C}$	-	700	V

Symbol	Parameter	Conditions		Min	Max	Unit
V _{TDS}	transient drain to source voltage	t _p < 200 μs	[1]	-	800	V
V _{GS}	gate-source voltage		[2]	-1.4	7	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; Fig. 1		-	47	W
I _D	drain current	V _{GS} = 6 V; T _{mb} = 25 °C; Fig. 2	[3]	-	6	A
I _{DM}	peak drain current	pulsed; t _p = 10 μs; T _{mb} = 25 °C; Fig. 3	[4]	-	10	A
		pulsed; t _p = 10 μs; T _{mb} = 125 °C; Fig. 4	[4]	-	6	A
T _{stg}	storage temperature			-55	150	°C
T _j	junction temperature			-55	150	°C
T _{slid(M)}	peak soldering temperature			-	260	°C

- [1] Intended for non-repetitive events
- [2] The minimum V_{GS} is clamped by ESD protection circuit
- [3] Limited by device saturation
- [4] Limit was extracted from characterization test, not measured during production



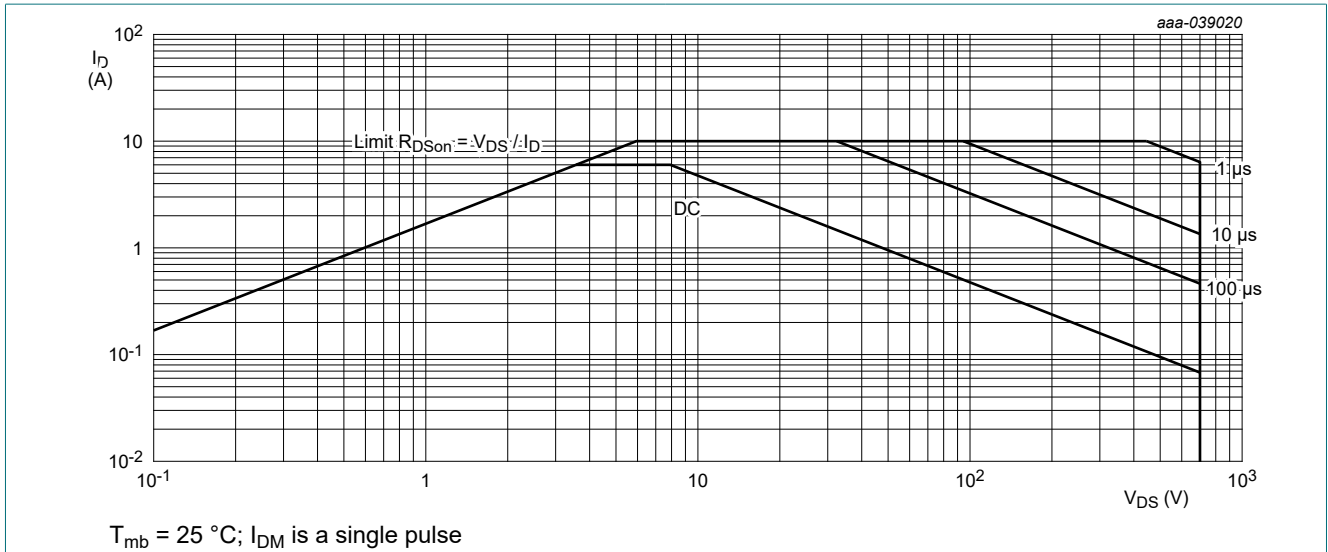


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

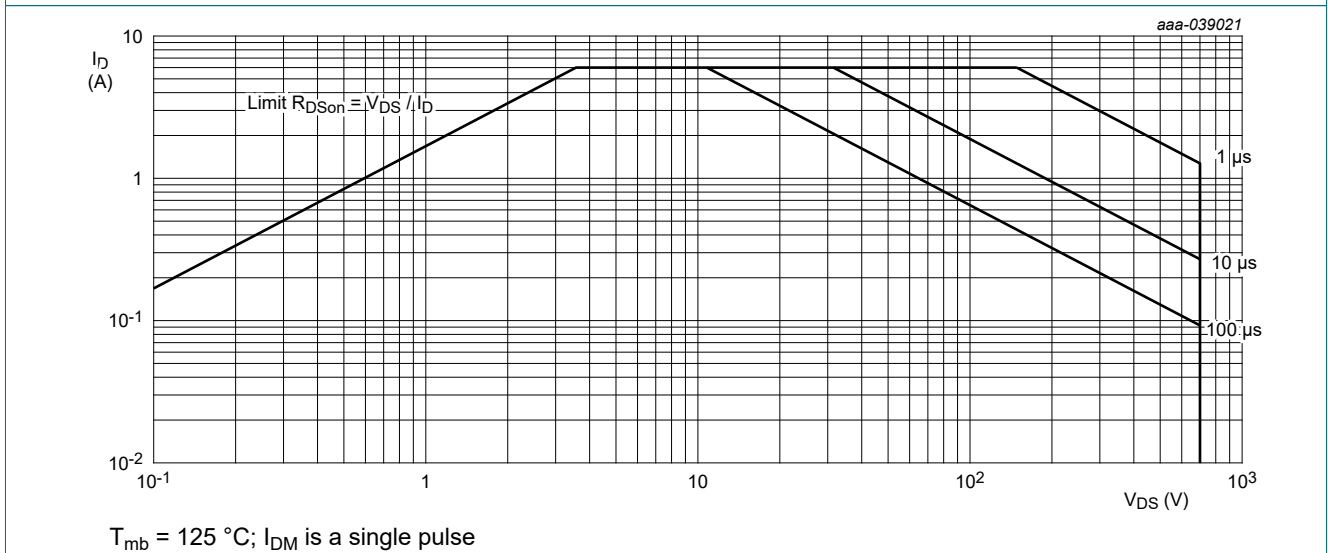


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5	-	-	2.63	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	[1]	-	-	56	K/W

[1] $R_{th(j-a)}$ is determined with the device mounted on one square inch of copper pad, single layer 2 oz copper on FR4 board.

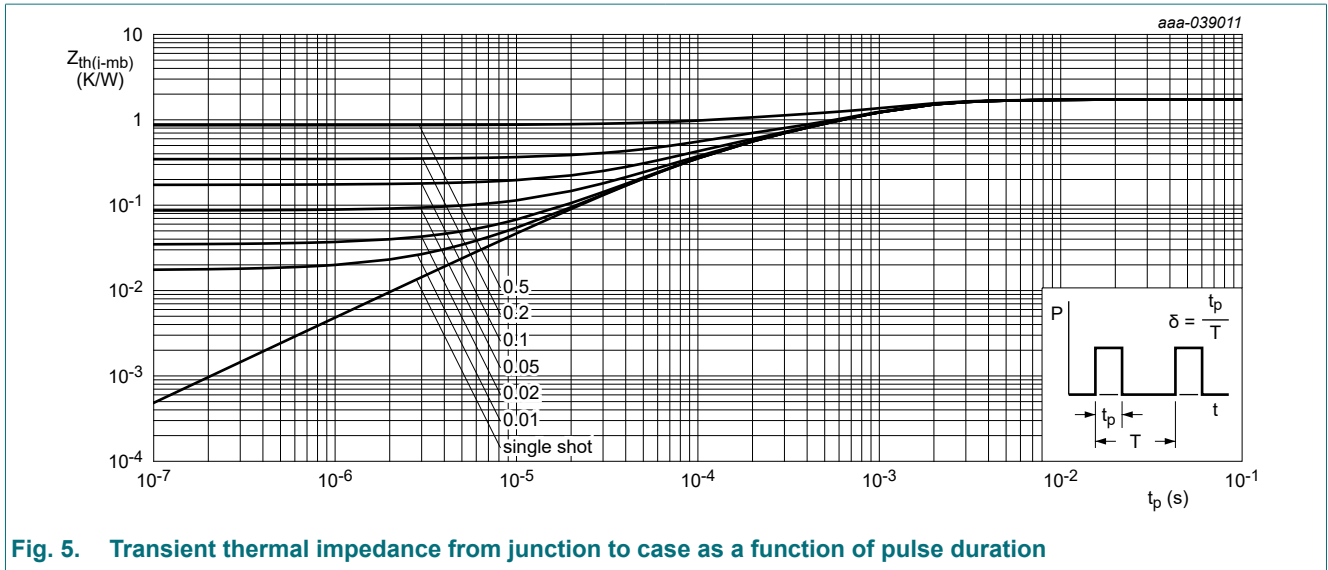


Fig. 5. Transient thermal impedance from junction to case as a function of pulse duration

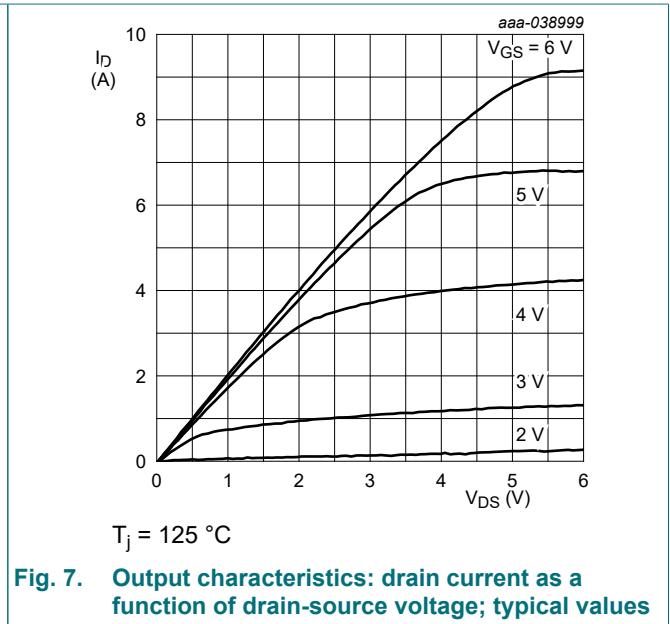
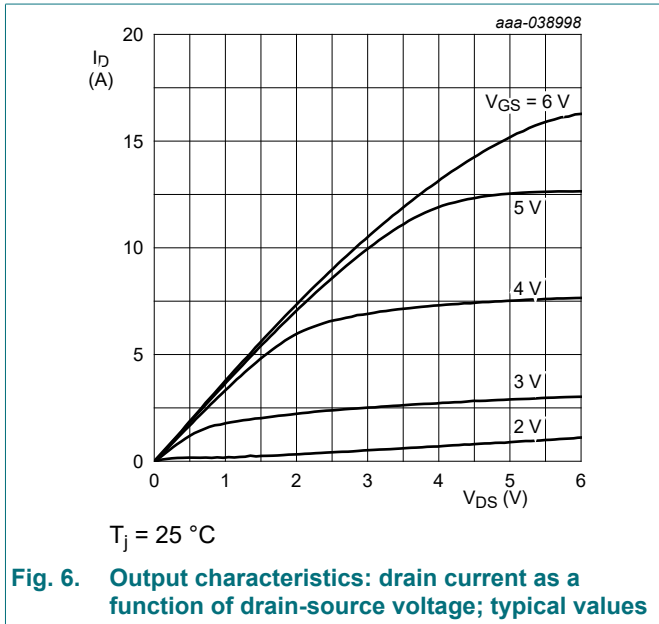
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 6.6 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 9	1.2	1.7	2.5	V
		$I_D = 6.6 \text{ mA}; V_{DS}=V_{GS}; T_j = 125 \text{ }^\circ\text{C};$ Fig. 9	-	1.7	-	V
I_{DSS}	drain leakage current	$V_{DS} = 700 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 10	-	0.6	12	μA
		$V_{DS} = 700 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ }^\circ\text{C};$ Fig. 10	-	5	-	μA
I_{GSS}	gate leakage current	$V_{GS} = 6 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 11	-	30	-	μA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 6 \text{ V}; I_D = 2.2 \text{ A}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 12; Fig. 13; Fig. 14	-	270	350	m Ω
		$V_{GS} = 6 \text{ V}; I_D = 2.2 \text{ A}; T_j = 150 \text{ }^\circ\text{C};$ Fig. 12; Fig. 15	-	580	-	m Ω
R_G	gate resistance	$f = 5 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C};$ open drain	-	11	-	Ω
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$I_D = 2.2 \text{ A}; V_{DS} = 400 \text{ V}; V_{GS} = 6 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 16; Fig. 17	-	1.5	-	nC
Q_{GS}	gate-source charge		-	0.15	-	nC
Q_{GD}	gate-drain charge		-	0.5	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 2.2 \text{ A}; V_{DS} = 400 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 17	-	2.2	-	V
C_{iss}	input capacitance	$V_{DS} = 400 \text{ V}; V_{GS} = 0 \text{ V}; f = 100 \text{ kHz}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 18	-	50	-	pF
C_{oss}	output capacitance		-	15	-	pF
C_{rss}	reverse transfer capacitance		-	0.2	-	pF
$C_{o(er)}$	effective output capacitance, energy related	$0 \text{ V} \leq V_{DS} \leq 400 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 19	[1]	20	-	pF

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$C_{o(tr)}$	effective output capacitance, time related	$0\text{ V} \leq V_{DS} \leq 400\text{ V}$; $V_{GS} = 0\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$	[2]	-	28	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 400\text{ V}$; $V_{GS} = 6\text{ V}$; $I_D = 4.4\text{ A}$; $L = 318\text{ }\mu\text{H}$; $R_{on} = 10\text{ }\Omega$; $R_{off} = 2\text{ }\Omega$; Fig. 20; Fig. 21	-	0.9	-	ns
t_r	rise time		-	3.5	-	ns
$t_{d(off)}$	turn-off delay time		-	1.2	-	ns
t_f	fall time		-	6.1	-	ns
Q_{oss}	output charge	$V_{GS} = 0\text{ V}$; $V_{DS} = 400\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 22	[3]	-	13	nC
Source-drain characteristics						
V_{SD}	source-drain voltage	$I_S = 2.2\text{ A}$; $V_{GS} = 0\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 23; Fig. 24; Fig. 25; Fig. 26	-	2.6	-	V

- [1] $C_{O(er)}$ is the fixed capacitance that gives the same stored energy as C_{OSS} while V_{DS} is rising from 0 to 400 V
- [2] $C_{O(tr)}$ is the fixed capacitance that gives the same charging time as C_{OSS} while V_{DS} is rising from 0 to 400 V
- [3] Q_r is not specified separately from Q_{oss} for e-mode GaN FETs, since $Q_r = Q_{oss} + Q_D$, and $Q_D = 0$. (Q_D is charge associated with diffusion of minority carriers. Since there is no body diode, no minority carriers in excess of Q_{oss} have to be transferred for e-mode GaN FETs.)



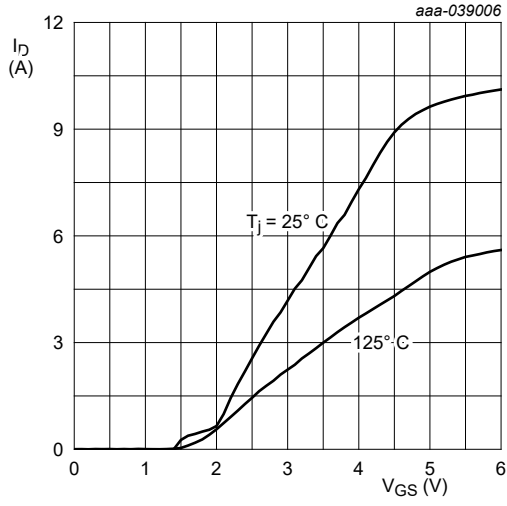


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

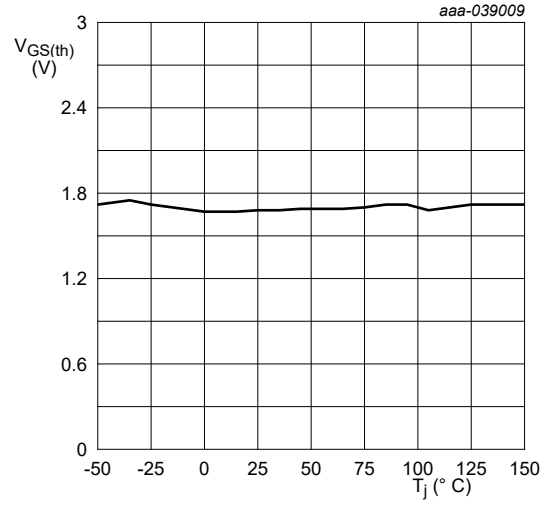


Fig. 9. Gate-source threshold voltage as a function of junction temperature; typical values

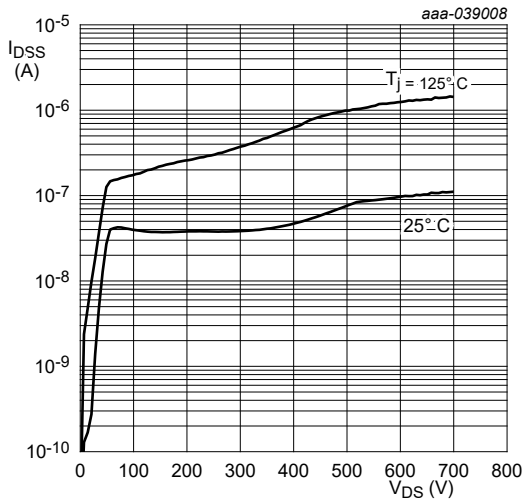


Fig. 10. Drain-source current as a function of drain-source voltage; typical values

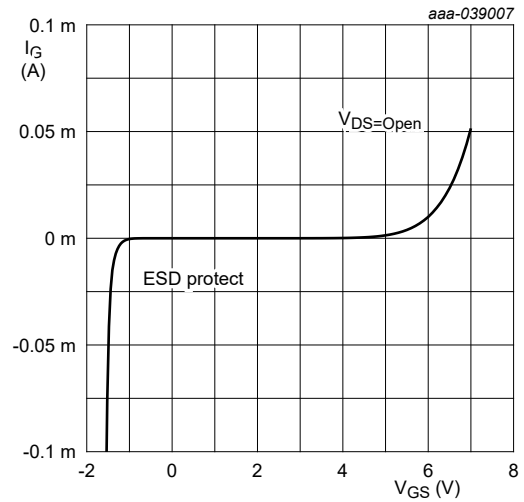
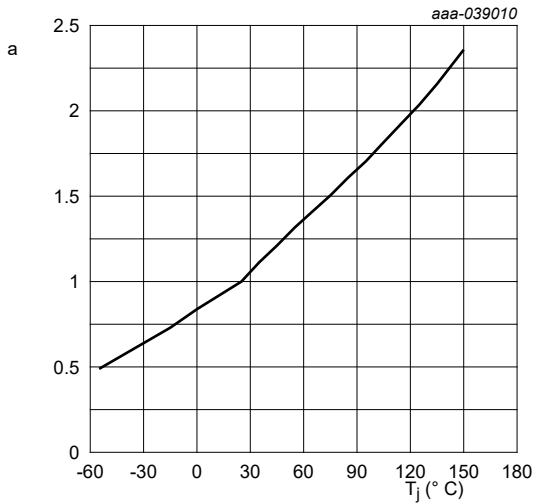
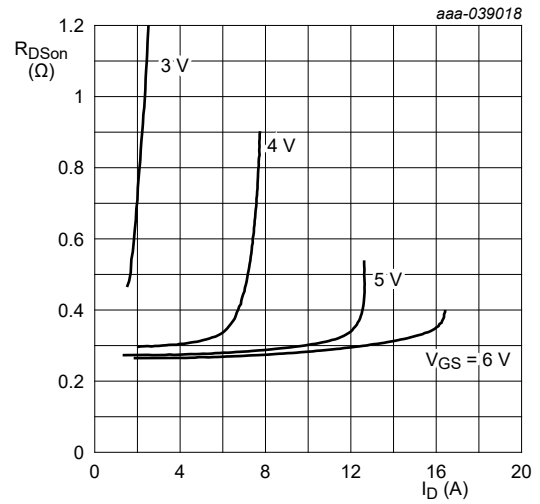


Fig. 11. Gate-source current as a function of gate-source voltage; typical values



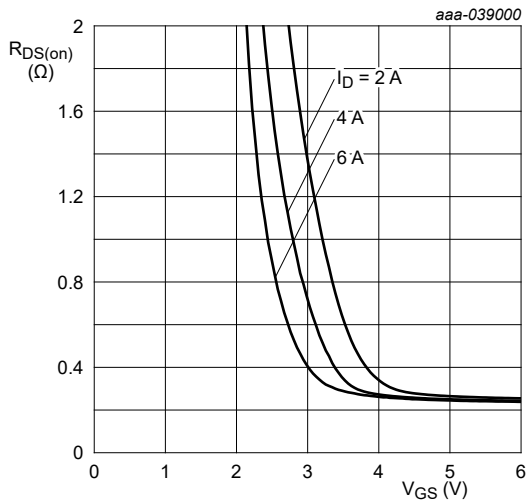
$$a = \frac{R_{DS(on)}}{R_{DS(on)(25^\circ\text{C})}}$$

Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature



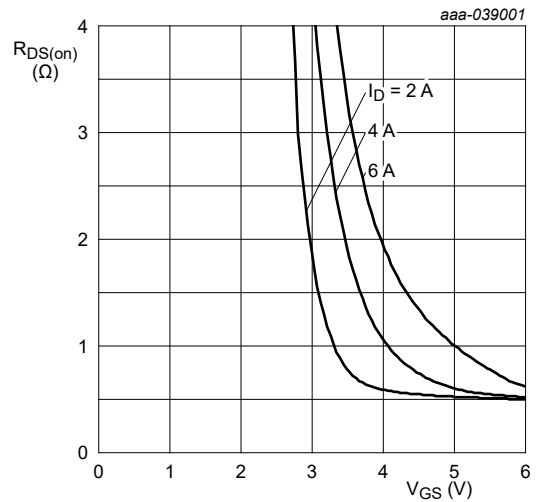
$T_j = 25^\circ\text{C}$

Fig. 13. Drain-source on-state resistance as a function of drain current ; typical values



$T_j = 25^\circ\text{C}$

Fig. 14. Drain-source on-state resistance as a function of gate-source voltage; typical values



$T_j = 125^\circ\text{C}$

Fig. 15. Drain-source on-state resistance as a function of gate-source voltage; typical values

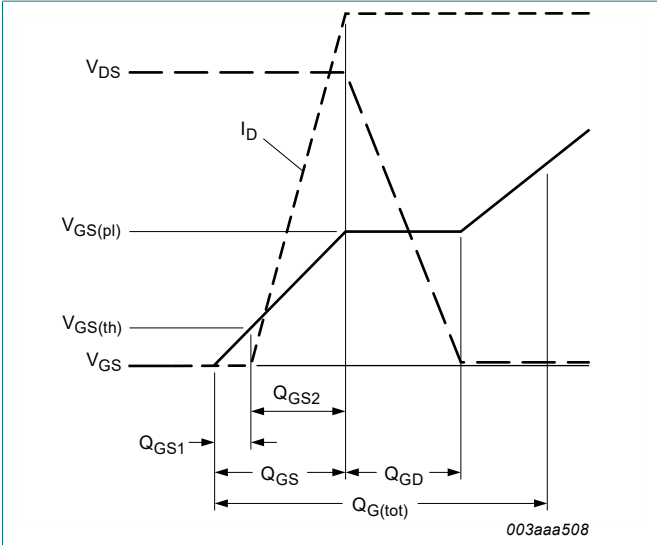


Fig. 16. Gate charge waveform definitions

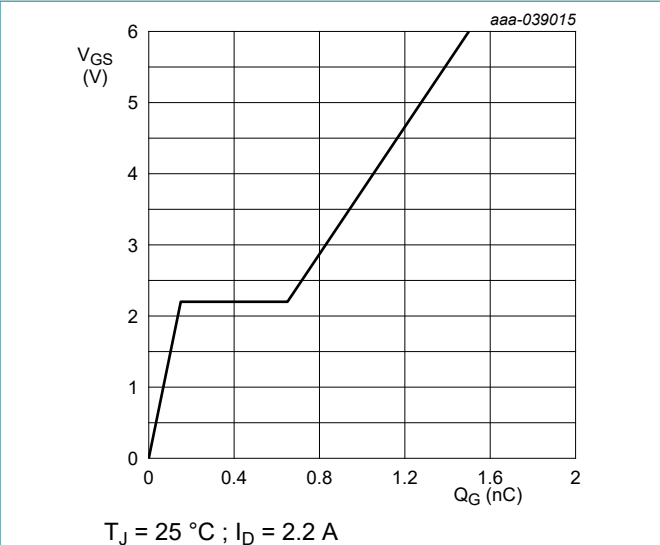


Fig. 17. Gate-source voltage as a function of gate charge; typical values

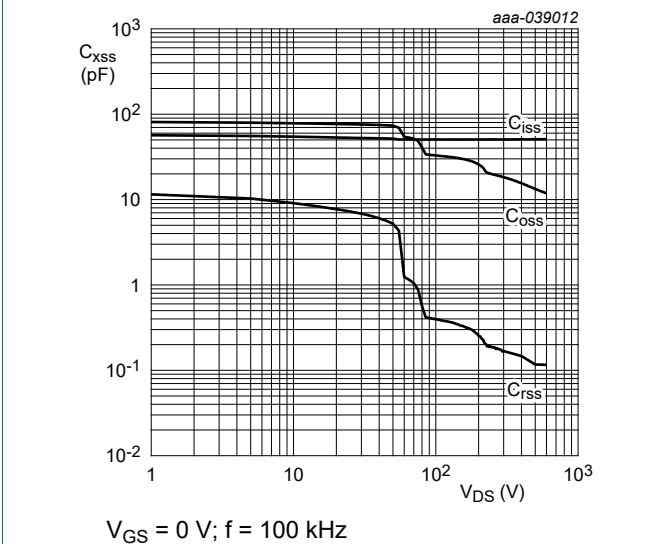


Fig. 18. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

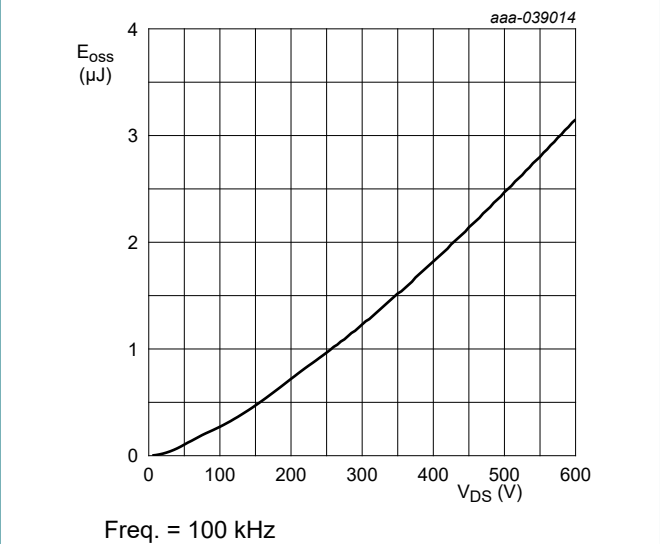


Fig. 19. COSS stored energy as a function of drain-source voltage; typical values

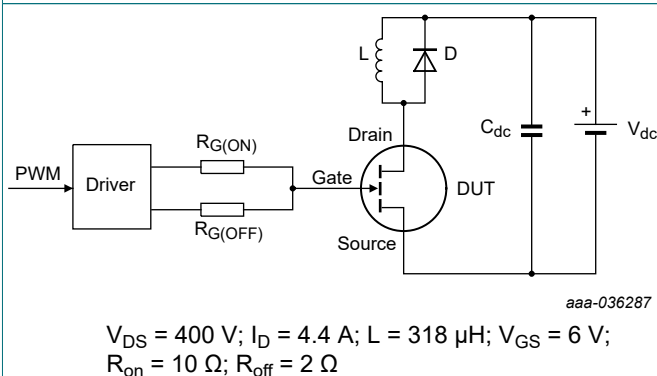


Fig. 20. Switching time test circuit with inductive load

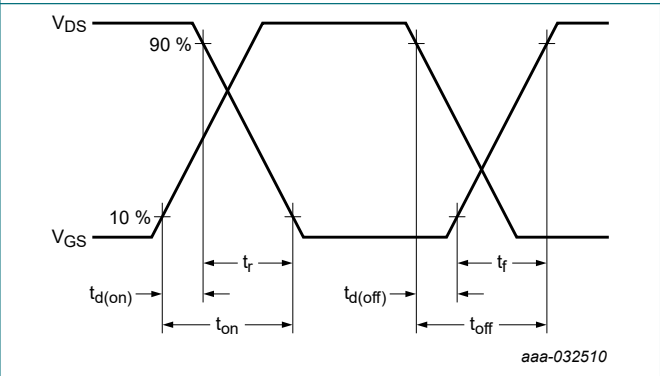
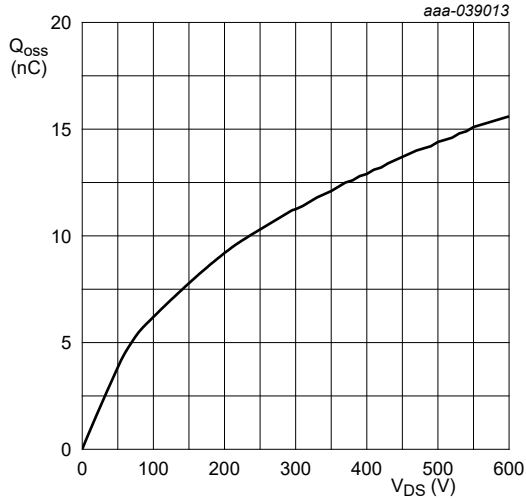
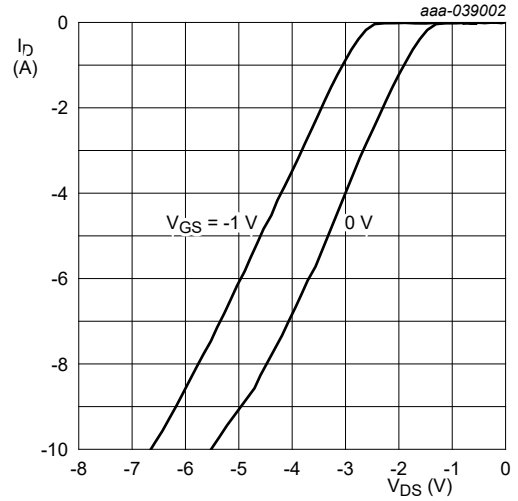


Fig. 21. Switching time waveform



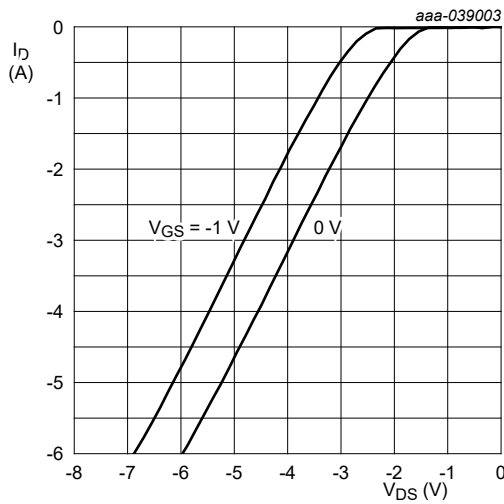
Freq. = 100 kHz

Fig. 22. Output charge as a function of drain-source voltage; typical values



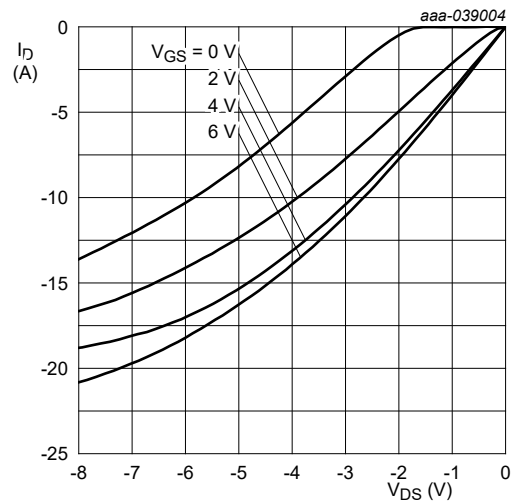
$T_j = 25\text{ °C}$

Fig. 23. Source current as a function of source-drain voltage; typical values



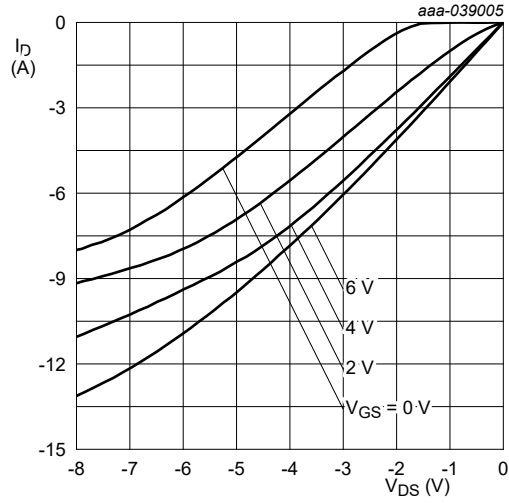
$T_j = 125\text{ °C}$

Fig. 24. Source current as a function of source-drain voltage; typical values



$T_j = 25\text{ °C}$

Fig. 25. Source current as a function of source-drain voltage; typical values



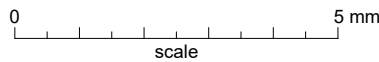
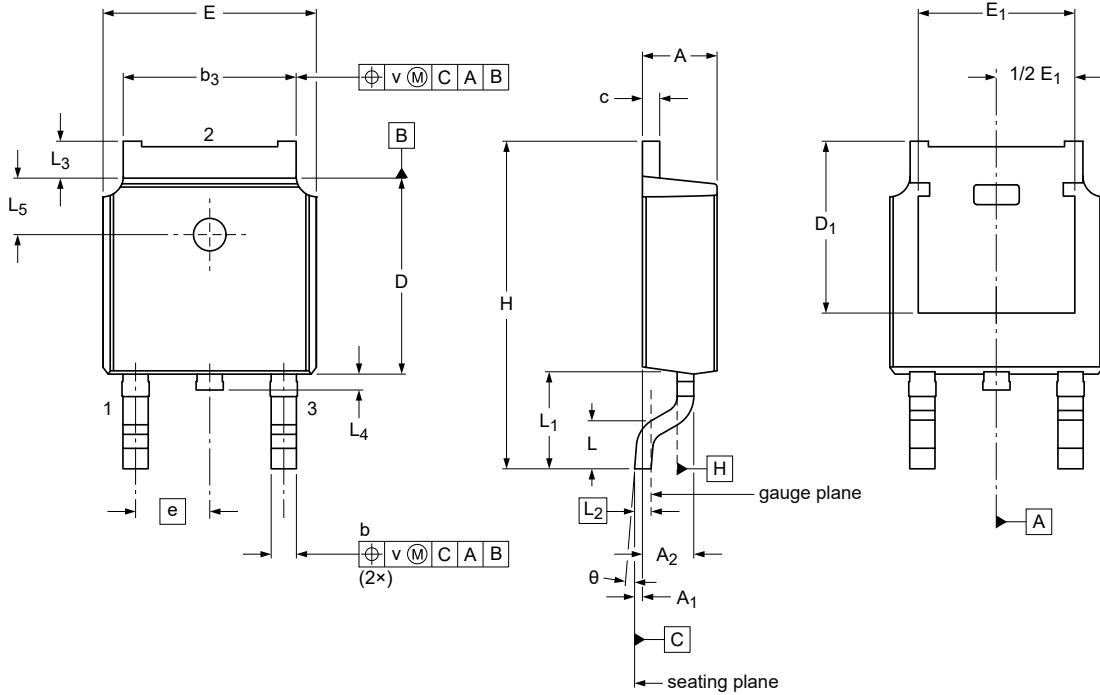
$T_j = 125\text{ }^\circ\text{C}$

Fig. 26. Source current as a function of source-drain voltage; typical values

11. Package outline

plastic, single-ended surface-mounted package (DPAK); 3 leads;
2.286 mm pitch; 6.1 mm x 6.6 mm x 2.3 mm body

SOT428-2



Dimensions (mm are the original dimensions)

Unit ⁽¹⁾	A	A ₁	A ₂	b	b ₃	c	D	D ₁	E	E ₁	e	H	L	(L ₁)	L ₂	L ₃	L ₄	L ₅	v	θ
max	2.40	0.13	1.17	0.90	5.46	0.61	6.22	5.30	6.73	4.83	2.286	10.50	1.75	2.90	0.51	1.28	1.00	1.95		8°
mm nom	2.30		1.07	0.78	5.33	0.53	6.10	REF	6.60	REF	BSC	10.10	1.50	REF	BSC			1.80	0.01	
min	2.20	0.00	0.92	0.63	5.10	0.43	5.98		6.40			9.40	1.38			0.88	0.50	1.65		0°

Note

- Dimensions do not include plastic protrusions.
- Package outline exclusive of metal burr dimensions.
- Datums A and B to be determined at datum plane H.

sot428-2_po

Outline version	References			European projection	Issue date
	IEC	JEDEC	JEITA		
SOT428-2					24-11-19

Fig. 27. Package outline TO252 (SOT428-2)

12. Soldering

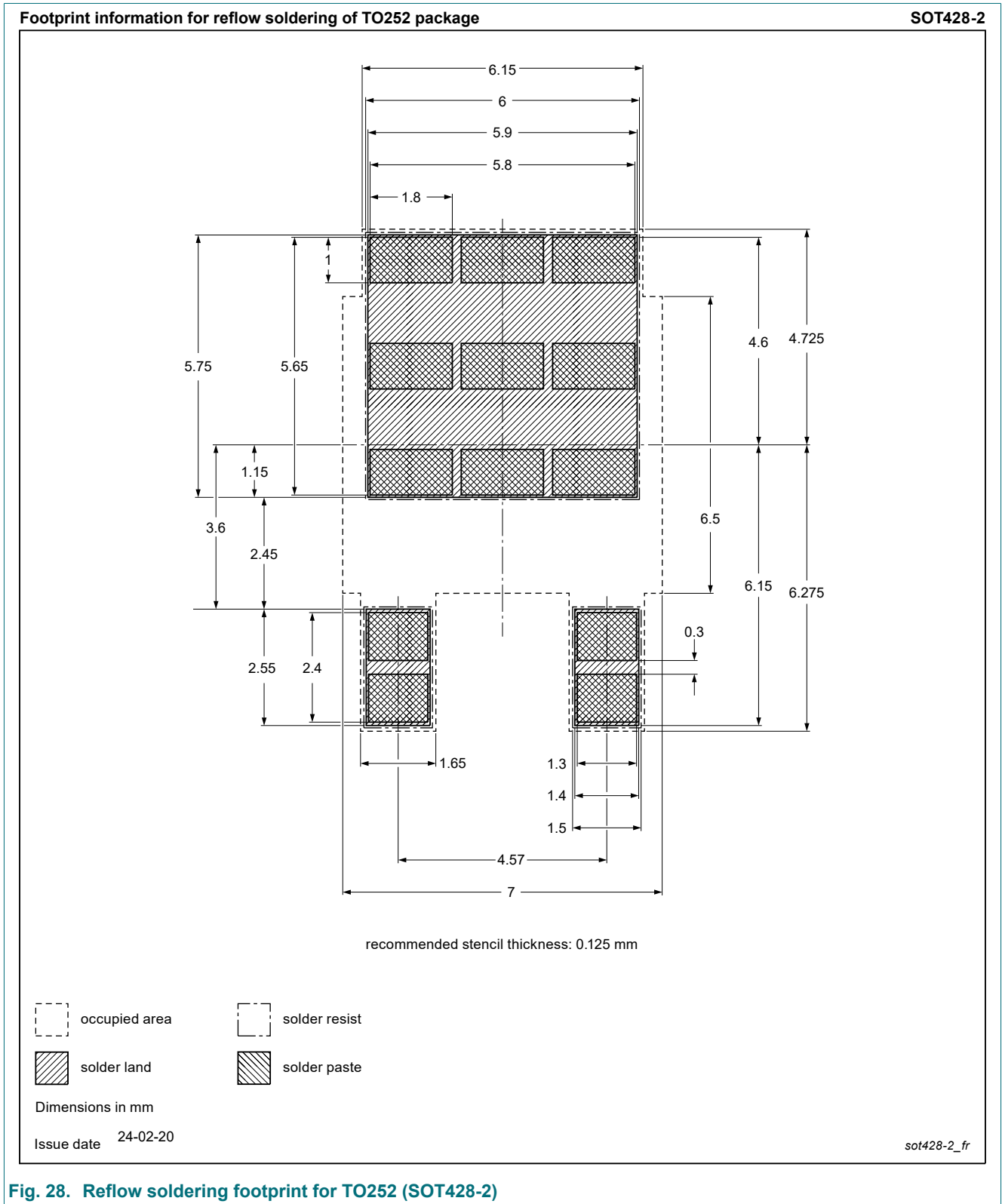


Fig. 28. Reflow soldering footprint for TO252 (SOT428-2)

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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